

# L20G20IS

### Ultra-compact two-axis gyroscope for optical image stabilization





### Features

- ±100 dps / ±200 dps full-scale range
- 5 degree phase delay
- 3.8 mdps/√(Hz) rate noise density
- Wide supply voltage range: 1.7 V to 3.6 V
- Low-voltage compatible IOs
- 3- and 4-wire SPI digital interface
- Embedded temperature sensor
- Embedded self-test
- Integrated low-pass filters with user-selectable bandwidth
- Power-down and sleep modes for smart power saving
- ECOPACK<sup>®</sup>, RoHS and "Green" compliant

### Applications

• Optical image stabilization

### Description

The L20G20IS is a two-axis MEMS gyroscope for optical image stabilization applications.

It includes a sensing element and an IC interface capable of providing the measured angular rate to the application through an SPI digital interface.

The unique sensing element is manufactured using a dedicated micromachining process developed by STMicroelectronics to produce inertial sensors and actuators on silicon wafers.

The IC interface is manufactured using a CMOS process that allows a high level of integration to design a dedicated circuit which is trimmed to better match the characteristics of the sensing element.

The L20G20IS is available in a plastic land grid array (LGA) package and can operate over a temperature range of -40 °C to +85 °C.

Order code	Temperature range (°C)	Package	Packing
L20G20IS	-40 to +85	(2.0 x 2.0 x 0.7) mm	Tray
L20G20ISTR	-40 to +85	(2.0 x 2.0 x 0.7) mm	Tape and reel

### Table 1. Device summary

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This is information on a product in full production.

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# 1 Block diagram and pin description

# 1.1 System block diagram





### 1.2 Pin description



Figure 2. Pin connections

1. Leave pin electrically unconnected and soldered to PCB.

Pin #	Pin name	Function
1	VDDIO	Power supply for I/O pins
2	SCL	Clock line for SPI interface
3	SDI/SDO	Serial data input (SDI) 3-wire interface serial data output (SDO)
4	SDO	Serial data output (SDO)
5	CS	Chip-select line
6	DRDY	Data ready signal
7	RES <sup>(1)</sup>	Leave unconnected
8	RES	Connect to GND
9	RES	Connect to GND
10	GND	0 V power supply
11	REG	Capacitance connection pin for internal regulator
12	VDD	Power supply

#### Table 2. Pin description

1. Leave pin electrically unconnected and soldered to PCB.



# 2 Mechanical and electrical specifications

### 2.1 Mechanical characteristics

The values listed in the table below are specified for Vdd = 2.4 V, Tamb = 25  $^{\circ}$ C unless otherwise specified.

Symbol	Parameter	Test condition	Min.	Typ. <sup>(1)</sup>	Max.	Unit
FS	Maggurament range			±100		dpa
г3	Measurement range			±200		- dps
So	Sensitivity	FS=±100 dps		262		LSB/dps
30		FS= ±200 dps		131		
So	Sensitivity initial tolerance <sup>(2)</sup>			±1.5		%
TSo	Sensitivity drift vs. temp. <sup>(3)</sup>	Delta from 25°C; range [-20°C to 75°C]		1		%
DVoff	Digital zero-rate level <sup>(4)</sup>			±5		dps
TDVoff	Digital zero-rate level drift vs. temp.	Delta from 25°C; range [-20°C to 75°C]		0.03		dps/°C
Rn	Rate noise density <sup>(5)</sup>	at 20 Hz		3.8		mdps/√(Hz)
PhD	Phase delay <sup>(6)</sup>	at 20 Hz (450 Hz BW selected)		5		deg
ODR	Output data rate			9.33		kHz
Ton	Turn-on time			35		ms
ST	Gyroscope self-test		20		90	dps
Тор	Operating temperature range		-40		+85	°C

Table 3	Mechanical	characteristics
Table 5.	Wechanica	characteristics

1. Typical specifications are not guaranteed.

2. Sensitivity value after factory calibration test and trimming.

3. Measurements are performed in a uniform temperature setup and they are based on characterization data with a limited number of samples, not measured during final test production.

4. Zero-rate level value after factory calibration test and trimming.

5. Guaranteed by design.

6. Refer to Section 4: L20G20IS filtering chain for filtering details.



### 2.2 Electrical characteristics

The values listed in the table below are specified for Vdd = 2.4 V, Tamb = 25  $^{\circ}$ C unless otherwise specified.

Symbol	Parameter	Test condition	Min.	Тур. <sup>(1)</sup>	Max.	Unit
VDD	Supply voltage		1.7		3.6	V
VDD_IO	I/O pins supply voltage		1.7		3.6	V
ldd	Supply current in normal mode			1.4		mA
IddPDN	Supply current in power-down mode			5		uA
V <sub>IH</sub>	Digital high-level input voltage		0.7 *VDD_IO			V
V <sub>IL</sub>	Digital low-level input voltage				0.3 *VDD_IO	V
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = 4 mA <sup>(2)</sup>	VDD_IO - 0.2			V
V <sub>OL</sub>	Low-level output voltage	I <sub>OL</sub> = 4 mA <sup>(2)</sup>			0.2	V
Тор	Operating temperature range		-40		+85	°C

1. Typical specifications are not guaranteed

2. 4 mA is the maximum driving capability, i.e. the maximum DC current that can be sourced/sunk by the digital pad in order to guarantee the correct digital output voltage levels  $V_{OH}$  and  $V_{OL}$ .

### 2.3 Temperature sensor characteristics

The values listed in the table below are specified for Vdd = 2.4 V, Tamb = 25  $^{\circ}$ C unless otherwise specified

Symbol	Parameter	Test condition	Min.	Typ. <sup>(1)</sup>	Max.	Unit
TSDr	Temperature sensor output change vs. temp			0.0625		°C/digit
TODR	Temperature refresh rate			70		Hz
TACC	Temperature absolute accuracy <sup>(2)</sup>			±4		°C
Тор	Operating temperature range		-40		+85	°C

#### Table 5. Temperature sensor characteristics

1. Typical specifications are not guaranteed

2. The output of the temperature is 0 at 25  $^\circ\text{C}.$ 



### 2.4 SPI - serial peripheral interface

Subject to general operating conditions for Vdd and Top.

Symbol	Parameter	Valu	Value <sup>(1)</sup>		
Symbol	Farameter	Min	Мах	Unit	
t <sub>c(SCL)</sub>	SPI clock cycle	100		ns	
f <sub>c(SCL)</sub>	SPI clock frequency		10	MHz	
t <sub>su(CS)</sub>	CS setup time	5			
t <sub>h(CS)</sub>	CS hold time	8			
t <sub>su(SI)</sub>	SDI input setup time	5			
t <sub>h(SI)</sub>	SDI input hold time	15		ns	
t <sub>v(SO)</sub>	SDO valid output time		50		
t <sub>h(SO)</sub>	SDO output hold time	6			
t <sub>dis(SO)</sub>	SDO output disable time		50		

Table	6. SPI	slave	timing	values
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1. Values are guaranteed at 10 MHz clock frequency for SPI, based on characterization results, not tested in production.



### Figure 3. SPI slave timing diagram

*Note: Measurement points are done at* 0.2*·Vdd\_IO and* 0.8*·Vdd\_IO, for both input and output ports.* 



### 2.5 Absolute maximum ratings

Stresses above those listed as "absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Ratings	Maximum value	Unit			
Power supply	-0.3 to 4.8	V			
Power supply for I/O pins	-0.3 to Vdd	V			
Input voltage on: (CS, SDI/SDO, SDO, SCL)	-0.3 to Vdd_IO +0.1	V			
Storage temperature range	-40 to +125	°C			
Acceleration g for 0.2 ms	10,000	g			
Electrostatic discharge protection	2 (HBM)	kV			
	Power supply Power supply for I/O pins Input voltage on: (CS, SDI/SDO, SDO, SCL) Storage temperature range Acceleration <i>g</i> for 0.2 ms	Power supply-0.3 to 4.8Power supply for I/O pins-0.3 to VddInput voltage on: (CS, SDI/SDO, SDO, SCL)-0.3 to Vdd_IO +0.1Storage temperature range-40 to +125Acceleration g for 0.2 ms10,000			

Table 7.	Absolute	maximum	ratings
	Absolute	maximum	radings

Note:

: Supply voltage on any pin should never exceed 4.8 V.

This device is sensitive to mechanical shock, improper handling can cause permanent damage to the part.



This device is sensitive to electrostatic discharge (ESD), improper handling can cause permanent damage to the part.



# 3 Terminology and functionality

### 3.1 Sensitivity

An angular rate gyroscope is a device that produces a positive-going digital output for counterclockwise rotation around the sensitive axis considered. Sensitivity describes the gain of the sensor and can be determined by applying a defined angular velocity to it. This value changes very little over temperature and time.

### 3.2 Zero-rate level

The zero-rate level describes the actual output signal if there is no angular rate present. The zero-rate level of highly accurate MEMS sensors is, to some extent, a result of stress to the sensor and therefore the zero-rate level can slightly change after mounting the sensor on a printed circuit board or after exposing it to extensive mechanical stress. This value changes very little over temperature and time.

### 3.3 Data-ready interrupt and synchronous reading

On the L20G20IS the angular rate data can be retrieved using a synchronous read. To perform a synchronous read, *CTRL4\_OIS (0Eh R/W)* (DRDY\_EN) has to be set to '1' in order to enable the data-ready interrupt on the DRDY pin (refer to *Figure 5*). To properly perform a synchronous read, the angular rate data have to be read every time the DRDY pin goes high.

The DRDY signal can be latched (default condition) or pulsed if *CTRL1\_OIS (0Bh R/W)*(DR\_DRDY) is set to '1'. When a latched condition is selected, the interrupt goes low when the high part of one of the output channels is read *X-axis angular rate data. The value is expressed as two's complement.* or *DATA\_STATUS\_OIS (0Ah R)* and returns high when new data is generated. When a pulsed condition is selected, the interrupt behavior is independent from the read operations and remains high for 75 µsec every time new data is generated. The DRDY pin is set by default as push-pull output, but it can be configured as open-drain output by setting *CTRL4\_OIS (0Eh R/W)* (DRDY\_OD) to '1'.

### 3.4 Temperature sensor

The temperature data can be retrieved from the *TEMP\_OUT\_L* (01h R), *TEMP\_OUT\_H* (02h R) registers, as two's complement data in 12-bit format left-justified. The output of the temperature sensor is 0 at 25 °C.



# 4 L20G20IS filtering chain

The filtering chain for the L20G20IS appears in the figure below.





Table 8. Digital LPF configuration

			-	
LPF_BW2	LPF_BW1	LPF_BW0	LPF BW [Hz]	Phase delay [°]
0	0	0	290	7 @ 20 Hz
0	0	1	210	9 @ 20 Hz
0	1	0	160	11 @ 20 Hz
0	1	1	450	5 @ 20 Hz
1	x	х	1150	1 @ 10 Hz

Table 9. Digital HPF configuration

HPF_BW[1:0]	HPF cutoff [Hz]
00	0.023
01	0.091
10	0.324
11	1.457



# 5 Application hints





1. Leave pin electrically unconnected and soldered to PCB.

Power supply decoupling capacitors (C1, 2) should be placed as near as possible to the supply pins on the device (common design practice).



# 5.1 Internal pin status

Table	10.	Internal	pin	status
			P	010100

Pin #	Pin name	Function	Status
1	VDDIO	Power supply for I/O pins	
2	SCL	Clock line for SPI interface	Default: input without pull-up
3	SDI/SDO	Serial data input (SDI) 3-wire interface serial data output (SDO)	Default: input without pull-up
4	SDO	Serial data output (SDO)	Default: input without pull-up
5	CS	Chip-select line	Default: input without pull-up
6	DRDY	Data ready signal	Default: push-pull to gnd
7	RES	Leave unconnected	Default: push-pull to gnd
8	RES	Connect to GND	Internally unconnected
9	RES	Connect to GND	Internally unconnected
10	GND	0 V power supply	
11	REG	Capacitance connection pin for internal regulator	
12	VDD	Power supply	



# 6 Digital interfaces

The registers embedded inside the L20G20IS may be accessed through the SPI serial interfaces.

Pin name	Pin description
CS	Chip-select line
SCL	SPI serial port clock
SDI/SDO	Serial data input (SDI) 3-wire interface serial data output (SDO)
SDO	Serial data output (SDO)

Table 11. Serial interface pin description

### 6.1 SPI bus interface

The SPI is a bus slave. The SPI allows to write and read the registers of the device.

The serial interface connects to applications using 4 wires: CS, SCL, SDI and SDO.

**CS** is the serial port enable and it is controlled by the SPI master. It goes low at the start of the transmission and goes back high at the end. **SCL** is the serial port clock and it is controlled by the SPI master. It is stopped high when **CS** is high (no transmission). **SDI** and **SDO** are respectively the serial port data input and output. Those lines are driven at the falling edge of **SCL** and should be captured at the rising edge of **SCL**.

Both the read register and write register commands are completed in 16 clock pulses or in multiples of 8 in case of multiple read/write bytes. Bit duration is the time between two falling edges of **SCL**. The first bit (bit 0) starts at the first falling edge of **SCL** after the falling edge of **CS** while the last bit (bit 15, bit 23, ...) starts at the last falling edge of **SCL** just before the rising edge of **CS**.

**bit 0**: RW bit. When 0, the data DI(7:0) is written into the device. When 1, the data DO(7:0) from the device is read. In latter case, the chip will drive SDO at the start of bit 8.

bit 1-7: address AD(6:0). This is the address field of the indexed register.

bit 8-15: data DI(7:0) (write mode). This is the data that is written into the device (MSb first).

bit 8-15: data DO(7:0) (read mode). This is the data that is read from the device (MSb first).

The function and the behavior of SDI and SDO remain unchanged.



### 6.1.1 SPI read

3-wire mode is entered by setting the (SIM) bit equal to '1' (SPI serial interface mode selection).



The SPI read command is performed with 16 clock pulses:

bit 0: READ bit. The value is 1.

*bit 1*:  $M\overline{S}$  bit. When 0, does not increment the address; when 1, increments the address in multiple reads.

bit 2-7: address AD(5:0). This is the address field of the indexed register.

*bit 8-15*: data DO(7:0) (read mode). This is the data that will be read from the device (MSb first).

A multiple read command is also available.



### 6.1.2 SPI write



The SPI write command is performed with 16 clock pulses. A multiple byte write command is performed by adding blocks of 8 clock pulses to the previous one.

*bit 0*: WRITE bit. The value is 0.

*bit 1*:  $M\overline{S}$  bit. When 0, does not increment the address; when 1, increments the address in multiple writes.

bit 2 -7: address AD(5:0). This is the address field of the indexed register.

*bit 8-15*: data DI(7:0) (write mode). This is the data that will be written inside the device (MSb first).

bit 16-... : data DI(...-8). Further data in multiple byte writes.







# 7 Register mapping

The device contains a set of registers which are used to control its behavior and to retrieve angular rate data. The register address, consisting of 8 bits, is used to identify them and to write the data through the serial interface.

Name	Туре	Register address [Hex]	Default [Hex]					
WHO_AM_I	r	00	DA					
TEMP_OUT_L	r	01	output					
TEMP_OUT_H	r	02	output					
OUT_X_L	r	03	output					
OUT_X_H	r	04	output					
OUT_Y_L	r	05	output					
OUT_Y_H	r	06	output					
DATA_STATUS_OIS	r	0A	output					
CTRL1_OIS	r/w	0B	00					
CTRL2_OIS	r/w	0C	00					
CTRL3_OIS	r/w	0D	00					
CTRL4_OIS	r/w	0E	00					
OFF_X	r/w	0F	00					
OFF_Y	r/w	10	00					
Reserved		11 to1E						
OIS_CFG_REG	r/w	1F	00					

Registers marked as Reserved must not be changed.Writing to those registers may cause permanent damage to the device.

To guarantee the proper behavior of the device, all register addresses not listed in the above table must not be accessed and the content stored in those registers must not be changed.



# 8 Register description

The device contains a set of registers which are used to control its behavior and to retrieve angular rate data. The register address, consisting of 8 bits, is used to identify them and to write the data through the serial interface.

# 8.1 WHO\_AM\_I (00h R)

Table 13. WHO_AM_I register							
1	1	0	1	1	0	1	0

# 8.2 TEMP\_OUT\_L (01h R), TEMP\_OUT\_H (02h R)

Table 14. TEMP_OUT_L register							
Temp3	Temp2	Temp1	Temp0	0	0	0	0

#### Table 15. TEMP\_OUT\_H register

Te	emp11	Temp10	Temp9	Temp8	Temp7	Temp6	Temp5	Temp4
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#### Table 16. TEMP\_OUT resolution

Temp11-Temp0	Temperature data.
	Refer to Section 2.3: Temperature sensor characteristics on how to read the
	temperature sensor output data.

### 8.3 OUT\_X\_L (03h R), OUT\_X\_H (04h R)

X-axis angular rate data. The value is expressed as two's complement.

# 8.4 OUT\_Y\_L (05h R), OUT\_Y\_H (06h R)

Y-axis angular rate data. The value is expressed as two's complement.



## 8.5 DATA\_STATUS\_OIS (0Ah R)

#### Table 17. DATA\_STATUS\_OIS register

XYOR_OIS	XOR_OIS	YOR_OIS	0	XYDA_OIS	XDA_OIS	YDA_OIS	0
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#### Table 18. DATA\_STATUS\_OIS description

XYOR	OIS chain global data overrun. Default value: 0
lois	(0: no overrun has occurred;
	1: a new set of data has overwritten the previous set before the read)
XOR	OIS chain X-axis data overrun. Default value: 0
OIS	(0: no overrun has occurred;
013	1: new X-axis data has overwritten a previous value before the read)
YOR	OIS Y-axis data overrun. Default value: 0
OIS	(0: no overrun has occurred;
	1: new Y-axis data has overwritten a previous value before the read)
XYDA_	OIS chain global new data available. Default value: 0
OIS	(0: a new set of data (X,Y axes) is not yet available;
	1: a new set of data (X,Y axes) is available)
XDA_	OIS chain X-axis new data available. Default value: 0
OIS	(0: new data for the X-axis is not yet available; 1: new data for the X-axis is available)
YDA_	OIS chain Y-axis new data available. Default value: 0
OIS	(0: new data for the Y-axis is not yet available; 1: new data for the Y-axis is available)

# 8.6 CTRL1\_OIS (0Bh R/W)

#### Table 19. CTRL1\_OIS register

BOOT	DR_ PULSED	BLE	SIM	ODU	ORIENT	PW1	PW0

#### Table 20. CTRL1\_OIS register description

BOOT	Reboot memory content. Default value: 0 (0: normal mode; 1: reboot memory content <sup>(1)</sup> )
DR_PULSED	DRDY signal pulsed. Default value: 0 (0: DRDY is latched; 1: DRDY is pulsed)
BLE	Big/Little Endian Data Selection. Default value 0 (0: Data LSbyte @lower address; 1: Data MSbyte @ lower address)
SIM	SPI Serial Interface Mode configuration. Default value: 0 (0: 4-wire interface; 1: 3-wire interface)
ODU	Output Data Update. Default value: 0 (0: output registers not updated until MSB and LSB have been read; 1: OIS output registers are updated continuously)
ORIENT	Directional orientation selection. Default value: 0 (0: X-axis - Y-axis; 1: Y-axis - X-axis)
PW[1:0]	Power mode selection. Default: 00 Refer to <i>Table 21</i> .

1. Boot request is executed as soon as internal oscillator is turned on. It is possible to set this bit while in power-down mode in which case it will be served at the next normal mode or sleep mode.



PW1 PW0		Operating mode selection
0	0	Power-down
0	1	Power-down
1	0	Sleep mode
1	1	Normal mode

#### Table 21. Operating mode selection

### 8.7 CTRL2\_OIS (0Ch R/W)

#### Table 22. CTRL2\_OIS register

SignX	SignY	LPF_BW1	LPF_BW0	0 <sup>(1)</sup>	HP_RST	SW_RST	HPF

1. This bit must be set to '0' for proper operation of the device.

#### Table 23. CTRL2\_OIS register description

SignX	X-axis angular rate sign selection. Default: 0 (0: sign not inverted; 1: sign inverted)					
SignY	Y-axis angular rate sign selection. Default: 0 (0: sign not inverted; 1: sign inverted)					
LPF_BW[1:0]	Low-pass filter bandwidth selection. Refer to <i>Figure 4</i> and <i>Table 24</i> .					
HP_RST	Reset high-pass filter. (0: disabled; 1: enabled)					
SW_RST	Software reset. (0: disabled; 1: enabled)					
HPF	Digital high-pass filter enable. Default: 0 (0: high-pass filter is disabled; 1: high-pass filter is enabled)					

#### Table 24. Digital LPF configuration

LPF_BW	2 LPF_BW1	1 LPF_BW0	LPF BW [Hz]	Phase delay [°]
0	0	0	290	7 @ 20 Hz
0	0	1	210	9 @ 20 Hz
0	1	0	160	11 @ 20 Hz
0	1	1	450	5 @ 20 Hz
1	x	x	1150	1 @ 10 Hz



### 8.8 CTRL3\_OIS (0Dh R/W)

#### Table 25. CTRL3\_OIS register

0 <sup>(1)</sup>	0 <sup>(1)</sup>	0 <sup>(1)</sup>	ST_SIGN	ST_EN	0 <sup>(1)</sup>	H_L_ACTIVE	LPF_BW2
------------------	------------------	------------------	---------	-------	------------------	------------	---------

1. These bits must be set to '0' for proper operation of the device

#### Table 26. CTRL3\_OIS register description

ST_SIGN	Self-test sign. Default value: 0
	(0: not inverted sign; 1: inverted sign)
ST EN	Self-test enable. Default value: 0
<u> </u>	(0: ST disabled; 1: ST enabled)
H L ACTIVE	Data-ready signal active level. Default value: 0
	(0: active high; 1: active low)
LPF_BW2	Low-pass filter bandwidth selection. Refer to <i>Figure 4</i> and <i>Table 24</i> .

### 8.9 CTRL4\_OIS (0Eh R/W)

#### Table 27. CTRL4\_OIS register

0 <sup>(1)</sup> 0 <sup>(1)</sup> 0 <sup>(1)</sup> DRDY_EN	) TEMP_DATA_ ON_DRDY DRDY_OD 0 <sup>(1)</sup>
--	--

1. These bits must be set to '0' for proper operation of the device.

#### Table 28. CTRL4\_OIS register description

DRDY_EN	Data ready enable on DRDY pin. Default: 0 (1: DRDY on pin). Refer to Section 3.3: Data-ready interrupt and synchronous reading
TEMP_DATA _ON_DRDY	Temperature data-ready signal on DRDY pad. (0: disabled; 1: enabled)
DRDY_OD	DRDY pin configuration. Default value: 0 (0: push-pull; 1: open drain)

# 8.10 OFF\_X (0Fh R/W)

#### Table 29. OFF\_X register

0 <sup>(1)</sup>	OFFX6	OFFX5	OFFX4	OFFX3	OFFX2	OFFX1	OFFX0
------------------	-------	-------	-------	-------	-------	-------	-------

1. This bit must be set to '0' for proper operation of the device

#### Table 30. OFF\_X register description

OFFX [6:0]	User offset correction for X-axis. Default value: 000 0000
	The value is expressed as two's complement.

The calibration step is -0.98 dps/LSB.



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# 8.11 OFF\_Y (10h R/W)

Table 31. OFF_Y register							
0 <sup>(1)</sup>	OFFY6	OFFY5	OFFY4	OFFY3	OFFY2	OFFY1	OFFY0

1. This bit must be set to '0' for proper operation of the device

Table 32. OFF	_Y register	description
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OFFY [6:0]	User offset correction for Y-axis. Default 000 0000	
0111[0.0]	The value is expressed at two's complement	

Calibration step is 0.98 dps/LSB.

### 8.12 OIS\_CFG\_REG (1Fh R/W)

#### Table 33. OIS\_CFG register

0 <sup>(1)</sup>	0 <sup>(1)</sup>	0 <sup>(1)</sup>	0 <sup>(1)</sup>	FS_SEL	0 <sup>(1)</sup>	HPF_BW[1]	HPF_BW[0]

1. These bits must be set to '0' for proper operation of the device

#### Table 34. OIS\_CFG register description

FS_SEL	Full-scale selection. Default value: 0 (0: ±100 dps; 1: ±200 dps)
HPF_BW[1:0]	Digital HPF cutoff selection. Refer to Table 35: Digital HPF configuration

#### Table 35. Digital HPF configuration

HPF_BW[1:0]	HPF cutoff [Hz]
00	0.023
01	0.091
10	0.324
11	1.457



## 9 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK is an ST trademark.

### 9.1 Soldering information

The LGA package is compliant with the ECOPACK<sup>®</sup>, RoHS and "Green" standard. It is qualified for soldering heat resistance according to JEDEC J-STD-020.

Land pattern and soldering recommendations are available at <u>www.st.com/mems</u>.

### 9.2 LGA-12 package



Figure 9. LGA-12: package outline and mechanical data



### 9.3 LGA-12 packing information



### Figure 10. Carrier tape information for LGA-12 package

### Figure 11. LGA-12 package orientation in carrier tape



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Figure 12. Reel information for carrier tape of LGA-12 package

Reel dimensions (mm)			
A (max)	330		
B (min)	1.5		
С	13 ±0.25		
D (min)	20.2		
N (min)	60		
G	12.4 +2/-0		
T (max)	18.4		



# 10 Revision history

Date	Revision	Changes
27-Jun-2016	1	Initial release
03-Jul-2017	2	Document status promoted to production data Updated Section 9: Package information

### Table 37. Document revision history



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